Vincotech

10-EY232PB006ME01-PN98F08T

target datasheet

***flow*DUAL E2 SiC**	**2300 V / 6 mΩ**

Topology features

- Gate Resistor
- Half Bridge
- Temperature sensor

Component features

- Fast intrinsic diode with low reverse recovery
- High blocking voltage with low on-resistance
- High speed switching with low capacitance

Housing features

- Base isolation: AlN
- Convex shaped substrate for superior thermal contact
- Compact housing
- CTI600 housing material
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

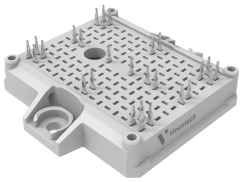
Target applications

- Charging Stations
- Energy Storage Systems
- General
- Industrial Drives
- Power Supply
- UPS
- Welding & Cutting

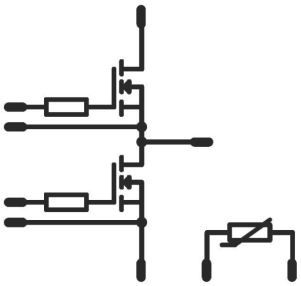
Types

- 10-EY232PB006ME01-PN98F08T

flow E2 12 mm housing



Schematic



Maximum Ratings

T_j = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Inverter Switch				
Drain-source voltage	V_{DSS}		2300	V
Drain current (DC current)	I_D	T_j = T_{jmax} T_s = 80 °C	388	A
Peak drain current	I_{DM}	t_p limited by T_{jmax}	830	A
Total power dissipation	P_{tot}	T_j = T_{jmax} T_s = 80 °C	525	W
Gate-source voltage	V_{GSS}		-4 / 15	V
		dynamic	-8 / 19	
Maximum Junction Temperature	T_{jmax}		175	°C
Resistor				
DC current	I	terminal temperature Tk = 90 C°	782	mA
Power dissipation	P_{tot}	T_j = T_{jmax} T_s = 80 °C	0,625	W
Operation Temperature	T_{op}		-55 ... 155	°C
Module Properties				
Thermal Properties				
Storage temperature	T_{stg}		-40…+125	°C
Operation temperature under switching condition	T_{jop}		-40…+(T_{jmax} - 25)	°C
Isolation Properties				
Isolation voltage	V_{isol}	DC Test Voltage t_p = 2 s	6800	V
Creepage distance			>12,7	mm
Clearance			9,05	mm
Comparative Tracking Index	CTI		≥ 600	

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	
Inverter Switch										
Static										
Drain-source on-state resistance	$r_{DS(on)}$		15		345	25		6	7,8	mΩ
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$			0,095	25	1,8	2,5	3,6	V
Gate to Source Leakage Current	I_{GSS}		15	0		25		50		nA
Zero Gate Voltage Drain Current	I_{DSS}		0	2300		25		5		µA
Internal gate resistance	r_g							2		Ω
Gate charge	Q_g		-4/15	1500	345	25		735		nC
Short-circuit input capacitance	C_{iss}	f = 100 kHz	0	1500	0	25		30000		pF
Short-circuit output capacitance	C_{oss}							510		
Reverse transfer capacitance	C_{rss}							50		
Diode forward voltage	V_{SD}		0		175	25		5,5		V
Thermal										
Thermal resistance junction to sink	$R_{th(j-s)}$	λ_{paste} = 5,2 W/mK (PTM)						0,18		K/W
Resistor										
Static										
Resistance	R							1,02		Ω
Tolerance							-5		5	%
Temperature coeficient	tc							200		ppm/K

Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_C [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max	
Thermistor										
Static										
Rated resistance	R					25		5		kΩ
Deviation of R100	$\Delta_{R/R}$	R_{100} = 499 Ω				100	3,2		3,3	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,3		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3380		K
Vincotech Thermistor Reference									V	

Ordering Code

Version	Ordering Code
Without thermal paste	10-EY232PB006ME01-PN98F08T
With thermal paste (5,2 W/mK, PTM6000HV)	10-EY232PB006ME01-PN98F08T-/7/

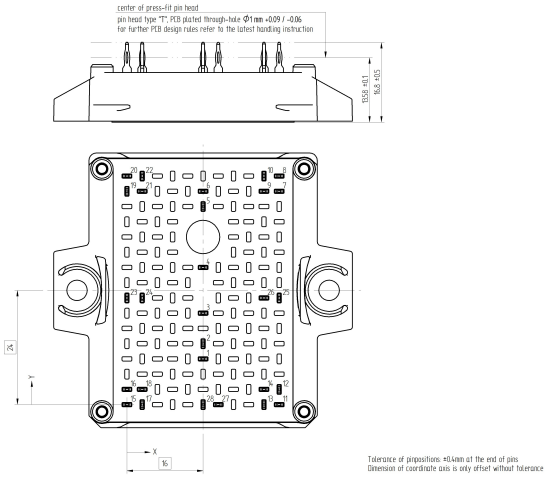
Marking

	Name		Date code	UL & VIN	Lot	Serial
Text	NN-NNNNNNNNNNNNNN-TTTTTTVV		WWYY	UL VIN	LLLLL	SSSS
Datamatrix	**Type&Ver**	**Lot number**	**Serial**	**Date code**		
	TTTTTTVV	LLLLL	SSSS	WWYY		

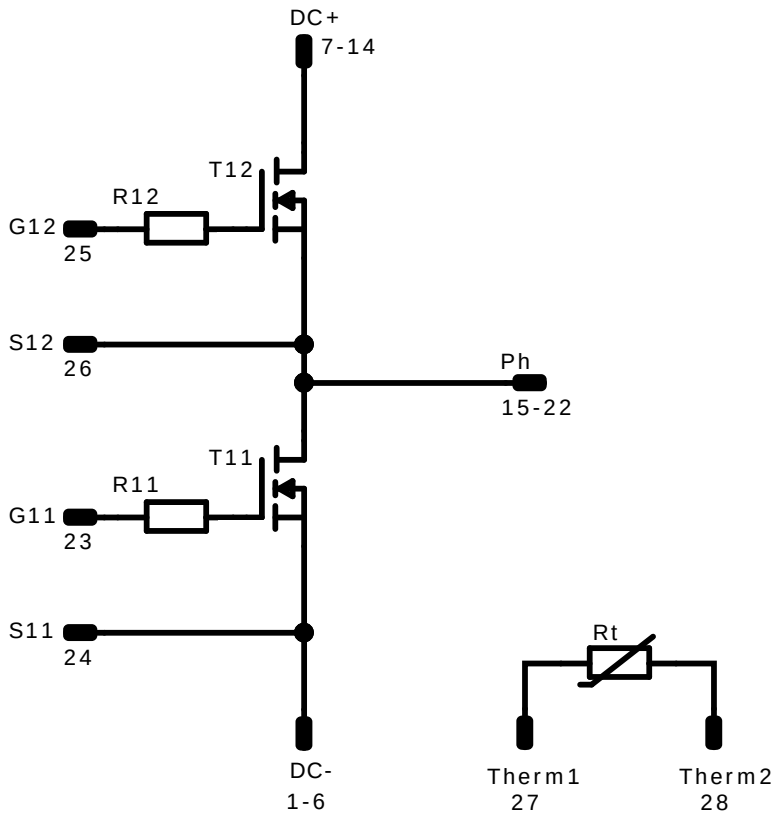
Outline

Pin table [mm]

Pin	X	Y	Function
1	16	9,6	DC-
2	16	12,8	DC-
3	16	19,2	DC-
4	16	28,8	DC-
5	16	41,6	DC-
6	16	44,8	DC-
7	32	44,8	DC+
8	32	48	DC+
9	28,8	44,8	DC+
10	28,8	48	DC+
11	32	0	DC+
12	32	3,2	DC+
13	28,8	0	DC+
14	28,8	3,2	DC+
15	0	0	Ph
16	0	3,2	Ph
17	3,2	0	Ph
18	3,2	3,2	Ph
19	0	44,8	Ph
20	0	48	Ph
21	3,2	44,8	Ph
22	3,2	48	Ph
23	0	22,4	G11
24	3,2	22,4	S11
25	32	22,4	G12
26	28,8	22,4	S12
27	19,2	0	Therm1
28	16	0	Therm2



Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
R11, R12	Resistor			Resistor	
T11, T12	MOSFET	2300 V	6 mΩ	Inverter Switch	
Rt	Thermistor			Thermistor	

Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for *flow* E2 packages see vincotech.com website.

Package data
Package data for *flow* E2 packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is UL 1557 recognized under E192116 up to a junction temperature under switching condition $T_{j,op}$=175°C and up to 4000VAC/1min isolation voltage. For more information see vincotech.com website.

Document No.:	Date:	Modification:	Pages
10-EY232PB006ME01-PN98F08T-T1-14	24 Jan. 2025	Initial Release	

Product status definition		
Datasheet Status	**Product Status**	**Definition**
Target	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. The data contained is exclusively intended for technically trained staff.